NSN 5961-00-237-1398

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View Online at https://aerobasegroup.com/nsn/5961-00-237-1398 **Inclosure Material:** Metal **Overall Length:** 0.150 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-52 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, collector-to-emitter, base open and 3.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 300.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 3300.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 25.0 small-signal short-circuit forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release5596 professional/industrial association specification Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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